

FCC ID: ALHTKR-820N-2 2.983 (d)(6) COMPONENTS

# **DESCRIPTION OF COMPONENTS**

## RX PLL: Z1, TX PLL: Z4 (X58-3120-10)

Ref. No.	Parts No.	Descriptions
IC1	MB504F	Prescaler
IC2	JLC1075F	PLL system
Q1	2SC3829TS	RF amplifier
Q2 ~ 5	DTC114EK	Inverter
D1	02CZ3.0(Z)	Level shifter

## RX VCO : Z2 (X58-3150-10)

Ref. No.	Parts No.	Descriptions	
Q1	25K508NV (K52)	Oscillator	
Q2, 3	2SC3356	Buffer amplifier	
Q4	2SC3099	Buffer amplifier	
D1	1SV166	Tuning	

#### TX VCO : Z5 (X58-3460-10)

Ref. No.	Parts No.	Descriptions
Q1	25K508 NV (KT2)	Oscillator
Q2	2SC3356	Buffer amplifier
Q3, 4	2SC3356	RF amplifier
D1	1SV166	Tuning
D2	1SV164	Modulator

#### MIC AMP: Z7 (X59-3210-10)

Ref. no.	Parts no.	Descriptions
IC1	NJM4560M	Mic amplifier/Limitter
IC2	NJM4558M	Limitter
1C3	NJM4558M	Active filter
Q1 ′	2SC3326(A)	Muting switch

### IF: Z8 (X59-3220-10)

Ref. No.	Parts No.	Descriptions
IC1	MC3361 8 B	IF system
Q1	2SC2712(Y)	Noise amplifier
D1	DA204K	Noise detector

#### BPF/VCA: Z9 (X59-3230-10)

Ref. No.	Parts No.	Descriptions
IC1	NJM4558M	Audio amplifier
IC2	NJM4558M	Active filter
IC3	M5222FP	Electronic attenuator
IC4	NJM4558M	Active filter



# **DESCRIPTION OF COMPONENTS**

#### AVR UNIT (X43-3040-10)

Ref. No.	Parts No.	Descriptions
Q1 ~ 3	2SC2712(Y)	DC amplifier
Ω4	2SB968(Q)	DC amplifier
Q5, 6	2N5885	DC amplifier
D1	1B2C1	Rectifier
D3	S25VB20	Rectifier
D4	1SS181	Temperature compensate
D5	RD7.5EB2	Voltage reference
D6	1SS181	Temperature compensate

#### FINAL UNIT (X45-3250-10)

Ref. No.	Parts No.	Descriptions
IC1	M57729H-01-P	TX power amplifier
Q1	2\$C3357	RF amplifier
Q2	2SC2954	RF amplifier
Ω3	2SB946(Q)	DC amplifier
Ω4	2SC2712(Y)	DC amplifier
Q5, 6	2SC3326(A)	DC amplifier
D1	1SV172	RF switch
D2	1\$S226	Voltage reference
D3, 4	1SS101	RF detect
D5	DSA3A1	Reverse polarity protection

## **SIGNALING UNIT (X52-3140-10)**

Ref. No.	Parts No.	Description
IC1	MC78L05M	Voltage regulator 5V
IC2	M51943BML	Reset system
IC3	BA4558F	Data recovery, active filter
IC4	BA4558F	Active filter
IC5	BA4558F	Data recovery
IC6, 7	BA4558F	Active filter
1C8	27C256QJESB	EPROM
IC9	TC74HC573AF	Data latch
IC10	BR93LC46	EEPROM
IC11	μPD78310 A GF	Microprocessor
Q1	DTC144EK	Level translator
Q2	DTC144EK	Inverter
Q3 ~ 7	DTC144EK	DC switch
Ω8	DTA114EK	DC switch
Q9	2SC3326(A)	Audio amplifier
Q1 <b>0</b>	2SJ106(GR)	Audio amplifier
D1, 2	1SS184	Current steering
D3	HSM88AS	Voltage clamp
D4 ~ 6	1SS184	Current steering
D7	B30-0838-05	LED (Red)

#### **DISPLAY UNIT (X54-3070-11)**

Ref. No. Parts No.		Descriptions
IC1	μPD75104GF - <b>J99</b>	Microprocessor
IC2	BR 93LC 46	EEPROM
IC3	M51943BML	Precision reference
IC4	AN78N05	Voltage regulator 5V
ÍC5	μPC4558C	Audio amplifier
IC6	μPC4558C	Active filter
Q1,2	DTC114EK	DC switch
Q3	2SA1162(Y)	Digital switch
Q4	DTC114EK	DC switch
Q6	2SC3326(A)	AF switch
Q7, 8	DTC114EK	DC switch
D1	B30-0855-05	LED (Red)
D2	830-0856-05	LED (Green)
D3	B30-0855-05	LED (Red)
D4 ~ 6	1SS184	Voltage clamp
D7, 8	1SS181	Current steering
D9	1\$1555	Current steering
D10, 11	1\$\$181	Current steering
D12	1SS184	Current steering
D13	1SS181	Current steering
D16	B30-0857-05	LED (Yellow)
D17	830-0856-05	LED (Green)
D18	830-0857-05	LED (Yellow)
D21	1SS272	Current steering

#### TX-RX UNIT (X57-3270-10)

Ref. No.	Parts No.	Descriptions
IC1	μPC1242H	AF power amplifier
IC2	MB3756	Voltage regulator
IC3	NJM4558D	AF amplifier
IC4	A)78N08	Voltage regulator
Q1,2	2SC2712(Y)	Voltage shift
Q3	2SC4093(R27)	RF amplifier
Q4,5	2SK125	IF amplifier
Q6	2SK302(GR)	IF amplifier
Q7	2SC2712(Y)	Level translator
<b>G</b> 8	DTC114EK	Inverter
Q9, 10	2SC3326(A)	Audio mute switch
Q11	DTC114EK	DC switch
Q12, 13	DTC114EK	Inverter
D1	1SV128	TX VCO output mute
D2	1\$V172	TX VCO output mute
D3	1\$\$226	Voltage clamp
D4	ND487C1T	Double balanced modulator
D5~9,11	1\$\$184	Current steering



# Test equipment required for alignment

	Test Equipment		Major Specifications
1.	Standard Signal Generator (SSG)	Frequency range Modulation Output	$400$ $\sim$ 512MHz Frequency modulation and external modulation. $0.1\mu$ V to greater than 1mV
2.	Power meter	Input impedance Operation frequency Measurement capabilit	50 ohms 4 o 0 to 512MHz or more.
3.	Deviation meter	Frequency range	400~512MHz
4.	Digital Volt Meter	Measuring range Accuracy	1~10V DC. High input impedance for minimum circuit loading.
5.	Oscilloscope		DC through 30MHz.
6.	High sensitivity frequency counter	Frequency range Frequency stability	10Hz to 600MHz. 0.2 ppm or less.
7.	Ammeter		15A.
•	AF Volt Meter (AFVTVM)	Frequency range Voltage range	50Hz to 10kHz. 3mV to 3V.
9.	Audio Generator (AG)	Frequency range Output	50Hz to 5kHz or more. 0 and 1V.
10.	Distortion meter	Capability Input level	3% or less at 1kHz. 50mV to 10Vrms.
11,	Voltmeter	Measuring range	10~1.5V DC or less. 50 kohms/V or greater.
12.	4 ohm dummy load		Approx. 4 ohm, 3W.

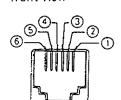
The set has been adjusted for the frequencies shown in the following table. When required, re-adjust them following the adjustment procedure to obtain the frequencies you want in actual operation.

		RX freq' (MHz)	TX freq' (MHz)
TKR-820	К	469.900	464.900
TKR-820	KZ	489.900	484900
TKR-820	وير	511.900	506.900
TKR-820	K4	429,900	424.900

### SIGNALING

сн	R)	<	TX				
L	QT (Hz)	DQT	QT (Hz)	DOT			
1	67		77				
2	192.8		179.9				
3		023		754			
4	88.5		167.9				
5	100			351			

# MIC connector front view



① SB

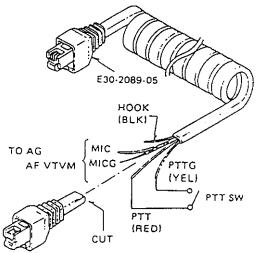
2 PTTG3 PTT

(4) MICG

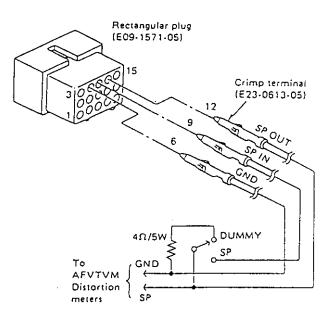
(5) MIC

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The following test cables are recommended.



Test cable for Microphone input

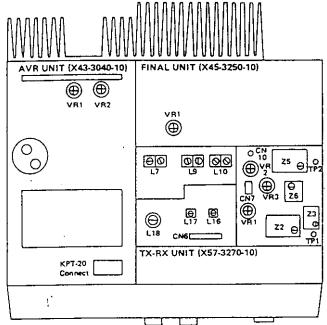


Test cable for Speaker output



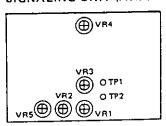
## Adjustment location

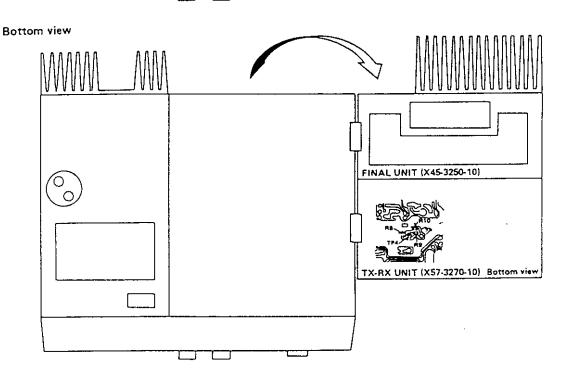
Top view



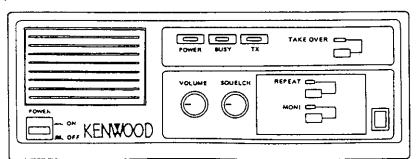
## Adjustment points

SIGNALING UNIT (X52-3140-10)





Front panel view





# lignment

								<u> </u>	
l tem	Condition	Test- equipmen	Uni		al Uni	t Pa		ustment Method	Specifications/Remarks
Setting	1) AC voltage for destination: 120V 2) Connect to the DC output (OUT terminal) and GND of the AVR unit. (+)			00 T	DVM TKE	DU1	мму Т	CLOAD (PLZ50-50)	AF VTVM DC AM METER
Test equip- ment set-up	1) Function: 0.10 resistor Meter: 60A, 60V DC: 0N Power: 0N SW1: 0FF					:			
Voltage setting	1) Power switch : ON	DVM		Output	AVR	VR1			13.6V ± 0.4V (Verify power indicator lights.)
	2) Vary the load for 2A — 10A draw. (Set to 10A after check.)	DVM AF VTVM							13.6V ± 0.7V DC Less than 30mV AC.
rotection	3) Power switch : OFF 1) SW1 : ON VR2 : MAX CW, Power switch : ON	DVM		Output	AVR	VR2	0.	2∨	0.2V ± 0.1V.
etGng	2) SW1: OFF  1) Write in freq' designed with EEP ROM writer. (For freq' writing, set the power of TKR-820 to ON.)  2) Connect the power cable to the rear panel.  3) Final unit VR1: MAX CCW.  4) TX-RX unit VR1: MAX CCW.  VR3: MAX CCW.  VR3: MAX CCW.		AG A	F VTVM	I GEO CONTRACTOR OF THE CONTRA	AC		•	Deviation meter    Deviation meter   Freq'   Counter   C
X PLL ock oltage	_	DVM	TX-RX	TPI	TX·RX	Z2	4.0	V ADJ.	0.1V
K PLL xck oltage		1	ſX-RX	TP2	TX·RX	<b>Z</b> 5	4.0	OV ADJ.	0.1V



• .		Measurement			A	djustment		
l tem	Condition	Test	Unit	Termina	⊌ Unit	Parts		Specifications/Remarks
3. TCXO Freq' ADJ.	1) PTT: OFF (RX)  Note: TCXO is adjusted precisely at 25°C. If it is readjusted, the frequency stability is changed.  Do not touch it normally.	Power meter FREQ' counter	TX-RX		TX-R		f = 21,4MHz ADJ.	
O. Transmit	1) PTT : ON	Power meter Ammeter	Rear	TX ANT		VR1	MAX CW. MIN 26W ADJ.	26Wor more. 2W or less. ± 1W
Freq' ADJ.		Power meter FREQ' counter	Rear	TNA XT	TX-RX	Z6	FREQ' ADJ. of TX.	± 100Hz
l, Tone deviation ADJ.	1) QT tone freq' being written. Deviation meter filter: LPF: 3kHz, HPF: OFF, De-emphasis: OFF PTT: ON	Power meter Deviation meter	Rear panel	TX ANT	Signal- ing	VR4	±0.75kHz	±100Hz
2. Maximum deviation ADJ.	1) Connect AG to the MIC terminal. AG: 1kHz/50mV Deviation meter filter: LPF: 20kHz, HPF: 50Hz, De-enphasis: 750µsec. TX-RX unit VR1: MAX CW. PTT: ON	Power meter Deviation meter	Rear panel	TNA XT	TX-RX	.	±2,1KHz ADJ. (±2,4kHz ADJ. In use of signaling.) Adjust one more than the other by switching between —P and +P.	±100Hz
sensitivity ADJ.	1) AG: 1kHz/5mV PTT: ON	, ,	Rear 7	X ANT	TX-RX	k	±1,5 KHz ADJ. ±1,95 K Hz ADJ. In use of signaling.)	± 100Hz
DQT waveform correction	PTT : ON	Power meter Deviation meter Oscillo- scope		Ţ	X-RX	r:	Make the demodu- ation waveform neat.	
RX sensitivity ADJ.		AF VTVM F 4Ω p dummy load	Rear E.	I .		F O	.78V/4Ω (Noise)	
			TKR-820			RX ANT ACC (SP)	4Ω dummy  AF VTV  Oscillosco	M Pe



ltem	Condin		Measurement				Adjustment					
	Condition		Test- lipment	Unit	Termi	nai (	Jnit	Parts			Specifications/Remark	
ļ	1) SSG output : 500µV/-53dBm MOD : OFF	SS( AF	VTVM	Rear Panel	EXT.S	_	(-RX		Reduce noise is using L7, L9 ar	evel	- Particel Military	
		met 4Ω	tortion er					L10	L10. Decrease the SS	j		
		dun load	• 1						output so that relevel is always 2	noise 10 to		
ļ.	2) SSG output :								30dB lower that	ļ		
1	500µV/—53d8m MOD : 1kHz/3kHz DE	,					ļ	18	Repeat 3 to 4 ti Adjust for maxis AF output.			
[3	) SSG output : 0.32µV/—117dBm	<del>`</del>					ļ		Adjust for maxir	num		
						Fron	it A	.17 .F	SINAD. 0.45V/4Ω ADJ.			
[4]	SSG output :					Fron			Check	SINA	AD 12dB or more.	
	500µV/—53d8m !					Panel	1	OL.	4.0V/4Ω ADJ. Check			
ich 1)	SSG output : OFF Rotate SQL VR to a point	SSG	Re	ar Ex	KT.SP	ļ ———			neck	Disto	45dB or more, ortion : 5% or less.	
	at which noise disappears.	4Ω dummy load	VM pa	nel						8:00	index angle ~ 10:00	
	SSG output : 0.2µV/-121dBm	Oscillo- scope								Squek	ch should open.	
h [	Signaling unit  VR1 to VR5 : MAX CCW SG output : OFF	ssg.			[	signal- ng				D7 : L	ED should light.	
2) S	SG output : 0.2µV/121dBm						VR	Ro	AX CW. tate VR1 CCW. a point at which	D7 : L	ED should go out.	
DJ. 1) S:	G output : 1.58µV/ 103dBm	DVM	Sign	II- TP2	s	gnal-	VR2		lights.	-		
0	ne set time can be intinuously varied by VR2. ~5V → 0 ~ 5sec.		ing		in	g			v	±0.1V		
R	G output : 501µV/-53dBm :PEAT SW : ON G output : OFF	Power meter SSG	Rear	TX A				Che	ck	TX LEC	) should light. T LED should light.	
1) The	set time can be									TX LED 1 sec. lat SSG OF	should go out about ser after turning F.	
0 ~	tinuously varied by VR3. 0.3V: OFF 0.5V: 30sec. 5V: ~ 5min.	DVM	Signati ing	TP1	Sig	nal- \	/R3	Set it time.	t to the target			
	output : 01μV/- 53d8m	Power meter SSG	Rear	EXT.S	P Sign	ial- V	'R5	± 1.5K	(Hz	± 100Hz		
	1	Deviation meter		1								



ltem	Condition	Measurement					Adjustm	ent	
		Test-	Unit	Termin	al Un			Method	Specifications/Remarks
21. Signaling squelch	1) SSG output: Turn the SSG output so that the SINAD sensitivity becomes 10dB.		<del>-</del>	<del></del>	AC 1k	Hz	0K	7	
	2) SSG MOD SW : EXT. MOD AG1 FREQ' : 1kHz AG2 FREQ' : QT tone freq'.				AG QT to (req'	}^ 2	0K WS	EXT. MOD	
	3) AG1: Power switch OFF. AG2 output: Adjust the output level of AG2 so that SSG deviation becomes 0.75kHz.		ΤK	R-820		R. Al	ACC (SP)		Ω dummy load  AF VTVM  Oscilloscope  istortion meter
	4) AG1: Power switch ON. AG1 output: Adjust the output level of AG1 so that the SSG deviation becomes 3.75kHz. (i.e., QT tone frequency/ 0.75kHz deviation, +1kHz/3kHz deviation) MONITOR SW: OFF		Rear panel	EXT.SP	Signal- ing		Check		Open.
Z TAKE- OVER				1	Front panel	TAKE- OVER switch	Check		The TAKEOVER LED must light on.

# CIRCUIT DESCRIPTION

#### **Transmitter Circuit**

The signal generated at the transmitter frequency synthesizer is amplified by RF amplifier transistors (Q1 and Q2) and amplifier module (IC1) to a level of 25W in the power amplifier unit. The signal is then routed to the antenna connector after going through a harmonics filter.

The transmitter output is detected by D3, 4 and is converted to a DC form. The DC signal thus detected is level adjusted by APC control (VR1) and is applied to the base of Q6. The base current of Q3 is varied according to the difference from the comparison voltage at Q5, 6 so that the collector voltages of Q2 and the IC1 first stage are controlled to maintain the transmitter output level constant.

In the event an abnormal temperature rise occurs, the temperature is sensed by a thermistor (TH1) and reduces the output power to a safe level.

The harmonics filter is of a fifth order Butterworth type lowpass filter having a minimum attenuation of more than 55dB at the second harmonics frequency with a passband insertion loss of less than 0.5dB. With a characteristics of the transmitter final power amplifier module, which has more than 30dB of attenuation for the frequency at the second harmonics or higher, total attenuation of harmonics is more than 70dB.

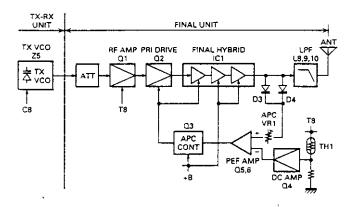


Fig. 1 Transmitter block diagram

#### **Receiver Circuit**

An incoming RF signal from the antenna is fed into a bandpass filter (L7). Then eliminated RF signal pass a protector (D3).

The signal is then amplified by an RF amplifier (Q3) and filtered again by bandpass filters (L9 and L10). After amplification and filtering, the signal is applied to a double balanced modulator (DBM, D4) for mixing with the first local signal generated at the Rx frequency synthesizer.

The heterodyning action of the first mixer produces a 21.4MHz first intermediate frequency (1st IF), which is applied to a 6-pole monolithic crystal filter (MCF, XF1) after being amplified by a buffer amplifier (Q4 and Q5 connected in parallel). The signal out of the MCF is further amplified by a 1st IF amplifier (Q6) and sent to the IF unit (Z8).

The signal applied to Z8 is mixed with a 20.945MHz signal at IC1 in Z8, which produces a 455kHz 2nd IF signal. The signal obtained at the 2nd mixer is filtered by a 455kHz ceramic filter (CF1) and amplified by limiting amplifier stages in IC1. The recovered audio signal from the incoming signal is also obtained at IC1 by a quadrature type FM detector. This recovered audio signal is then sent to the audio amplifier circuit and to the noise actuated squelch circuit.

In the receiver audio amplifier section, the recovered audio signal from Z8 is first applied to a bandpass filter/voltage controlled amplifier (BPF/VCA, Z9) unit. At this BPF/VCA unit, the signal is amplified and sent to pin 9 of CN6 as the DET signal. The signal is returned to Z9 by way of the Signaling unit. IC1 forms a lowpass filter and a highpass filter, and IC2 forms a bandpass filter and lowpass filter in Z9. The frequency components below 300Hz and above 3000Hz are attenuated in the above filter circuits.

The filtered audio signal is then applied to an electronic volume control (IC3), where the audio signal level is controlled by a DC voltage sent from the front panel volume control. The signal is then de-emphasized and sent to the audio power amplifier circuit (IC1) after going through squelch switches (Q9 and Q10).

The alert signal is also applied to IC1, when a specific signaling board, which requires an audible alert through the speaker, is installed. The signal, which is amplified by IC1, drives either the internal speaker or the optional external speaker and this selection is done through the accessory connector located on the Final unit.

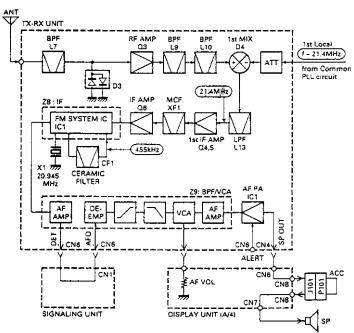


Fig. 2 Receiver block diagram

# TKR-820

# CIRCUIT DESCRIPTION

### **Squelch Circuit**

The high frequency component of the recovered audio signal is fed to a noise amplifier within IC1 of Z8 and it is further amplified by an external noise amplifier (Q1). The signal is then detected by a noise detector (D1) and applied to the squelch switch in IC1. This detected noise is also routed to the squelch control (VR3) through the Display unit (C/4) for adjusting the noise squelch sensitivity.

The busy information is sent from the above IC1 in the Display unit in serial format to turn on or off the busy LED. The squelch switch output and the audio control (AC) signal from the signaling board are combined at D8 and applied to

squelch switch transistors Q9 and Q10 along with the inverted signal of transmit/receive control signal. The squelch switch controls the input signal to the audio amplifier to mute or unmute the receive audio.

While the busy LED is being controlled only by the noise squelch circuit, the actual audio signal is controlled by the following signals and in order to unmute the audio, each signal must be in the condition as specified.

SQL signal = Low R8 line = High T/R signal = High AC signal = Low

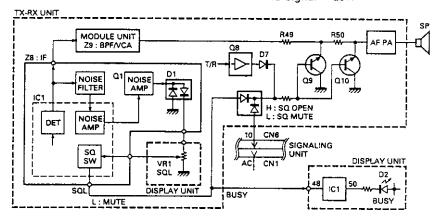


Fig. 3 Squelch circuit

### **RX Frequency Synthesizer**

The RX frequency synthesizer consists of three major circuits. They are the temperature compensated crystal oscillator (TCXO, Z3), RX voltage controlled oscillator (RX VCO, Z2) and RX phase locked loop unit (RX PLL, Z1).

The TCXO is operating at 12.8MHz and its frequency stability is maintained within  $\pm 2.5$ ppm from  $-30^{\circ}$ C to  $+60^{\circ}$ C. This output signal is fed to the frequency synthesizer IC (IC2) in Z1. At IC2, this signal is divided by 1024 to become a 12.5kHz reference signal.

The output from the RX VCO operates at the frequency of the receiver first local signal and a portion of the signal is fed to a dual modulus counter formed by IC1 and IC2 in Z1. IC1 divides the incoming signal by 1/64 or 1/65 depending on the control line status sent from IC2. The output of the dual modulus counter is also a 12.5kHz and this signal is compared against the 12.5kHz reference signal in a phase comparator at IC2: The output signal from the phase comparator is then fed back to the RX VCO after going through a charge pump and a lowpass filter to maintain the RX VCO frequency.

If this RX frequency synthesizer phase locked loop becomes UNLOCK, the unlock condition is detected by IC2 and it prevents the transmitter frequency synthesizer from sending a transmitter signal to following amplifier stages in order to prevent an unauthorized transmission.

## TX Frequency Synthesizer

The TX frequency synthesizer consists of three major circuits. They are the modulator/voltage controlled crystal oscillator (VCXO, Z6), TX voltage controlled oscillator (TX VCO, Z5) and TX phase locked loop unit (TX PLL, Z4).

The audio signal from the microphone amplifier and the Signaling unit is applied to the TX VCO (Z5) and the VCXO (Z6) operating at 12.8MHz to obtain an FM modulated signal. And its frequency stability is maintained within ±2.5ppm from -30°C to +60°C. This output signal is fed to the frequency synthesizer IC (IC2) in Z4. At IC2, this signal is divided by 1024 to become a 12.5kHz reference signal.

The output from the TX VCO operates at the frequency of the transmit signal and a portion of the signal is fed to a dual modulus counter formed by IC1 and IC2 in Z4. IC1 divides the incoming signal by 1/64 and 1/65 depending on the control line status sent from IC2. The output of the dual modulus counter is also a 12.5kHz and this signal is compared against the 12.5kHz reference signal in a phase comparator at IC2. The output signal from the phase comparator is then fed back to the TX VCO after going through a charge pump and a lowpass filter to maintain the TX VCO frequency.

If this TX frequency synthesizer phase locked loop becomes UNLOCK, the unlock condition is detected by IC2 and it prevents the transmitter frequency synthesizer from sending a transmitter.

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# **CIRCUIT DESCRIPTION**

## Microphone Amplifier

The audio signal originating at the microphone is applied to a microphone amplifier unit (Z7) after going through a microphone sensitivity control (VR1).

The signal is amplified and voltage limited by IC1 and IC2 in Z7, then applied to an active lowpass filter/pre-emphasis network (IC3).

The processed audio signal is sent to the modulator/voltage controlled crystal oscillator (VCXO, Z6) and voltage controlled oscillator (TX VCO, Z5) in the transmitter frequency synthesizer via IC3.

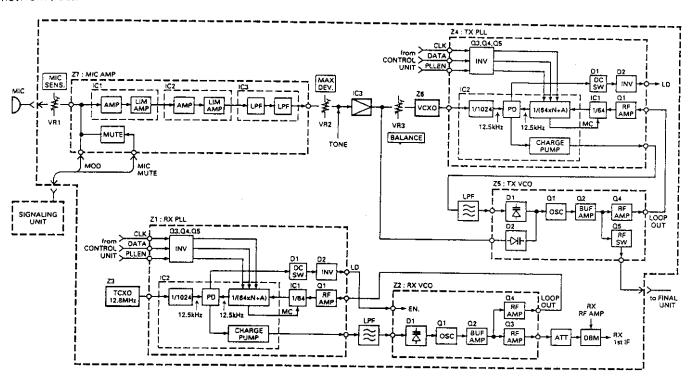
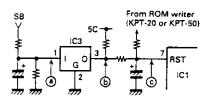


Fig. 4 PLL & Modulation circuit block diagram

### **Reset Circuit**

Upon initial power up, the line voltage gradually increases and this causes the reset system (IC3) to generate a reset pulse. This reset pulse is applied to the microprocessor (IC1) to insure the initialization of the circuit.



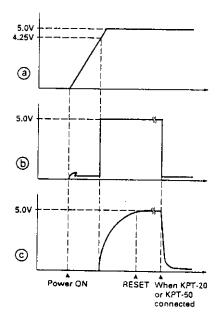


Fig. 5 Reset circuit block diagram

# TKR-820

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# **CIRCUIT DESCRIPTION**

## **AVR Circuit**

This power supply uses a tapped secondary transformer to maintain low voltage between the pass transistor collectors and emitters (Q5 and Q6) for excellent efficiency. Control and operating voltages are rectified and supplied independently for good ripple characteristics.

Temperature compensation for the regulator Zener diode D5 and error amplifier transistor Q4 is provided by silicon diodes D4 and D6.

At initial POWER-ON Q3 is ON to turn-down Q4 base voltage. This prevents a surge voltage from being output when no load is connected. As C5 charges, Q2 turns ON to shut Q3 OFF. Q4 is thereafter fully ON.

If the load is shorted, comparator Q1 is turned OFF and current proportional only to that in the initial turn-on circuit is output. When the output is shorted, the output current drops to 1A. This circuit protects the pass transistors, transformer and full wave bridge rectifies from thermal damage.

Changing between AC and DC is done with the DC switch (D101) for the TKR-820A only. The output from the AVR unit and the DC input from the external power input terminals are changed automatically.

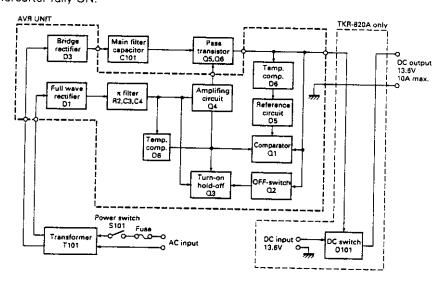


Fig. 6 AVR circuit block diagram

# TKR-820

# **CIRCUIT DESCRIPTION**

## **EEPROM Programming**

Programming of data into the EEPROM (IC2) in the Display unit is done by connecting the KPT-20 programmer to the transceiver by cable provided with the KPT-20 or KPT-50. When the programmer is connected to CN1 in the Display unit, this causes microprocessor IC1 to go into reset condition. In the reset condition, the output ports of IC1 becomes high impedance and are isolated from the data transfer lines. This permits data transfers between the programmer and the EEPROM.

### Signaling Unit

#### Decoder operation

The receive audio signal from the receiver section is fed to the Signaling unit. A part of this signal is returned to the receive audio amplifier circuit and fed to mute circuit after going through an active high-pass filter, in which any frequencies below 300Hz are removed. The mute circuit control a transfer audio signal by microprocessor. The other part of the audio signal is fed through a fifth-order active low-pass filter, of which the cut-off frequency is set at 220Hz, to discriminate the QT and DQT signals from other audio signals.

The QT tone obtained from the above filtered audio signal is applied to the microprocessor (IC11) as an analog signal for tone detection after being amplified by IC4 (2/2).

The DQT code is passed through a low-pass filter IC3 (2/2), of which the cut-off frequency is 140Hz, and the circuit consists of IC3 (1/2) and IC5 (1/2), where the DC drift component (low frequency) is removed from the signal. The signal is then amplified by IC5 (2/2). The amplified signal is applied to IC1 after waveform shaping by Q2.

IC11 sends an audio control signal (AC) to the AC terminal of CN1 through an inverter (Q4) according to the status of the incoming signal. If the incoming QT tone or DQT code matches the data stored, the AC terminal of CN1 is forced to become "LOW" to unmute the receive audio circuit.

#### Monitor circuit

The RESET terminal of CN1 is connected to the MONITOR and MIC MONITOR circuits in the repeater.

The RESET terminal signal level goes to "HiGH" state, if either the MONITOR switch is on or the microphones MONITOR switch is on, causing pin 4 (RESET) of IC11 to become "HIGH". In this condition, the AC terminal of CN1 is held "LOW", enabling only the noise actuated squelch operation.

#### Encoder operation

In the transmit mode, the PTT terminal of CN1 becomes "LOW" and this information is inverted to "HIGH" by Q7 before being applied to IC11. Upon receipt of this PTT signal or when the programmed tone has been decoded at the time of the REPEAT operation, IC11 starts the encode function. The encode signal is sent out from output ports, A/D 0 through A/D 7, of IC11 in a binary format and is fed to a ladder network resistor (CP1) for Digital-to-Analog signal conversion. The output signal from CP1, which is either the QT tone or the DQT code, is routed to the TONE terminal of CN1 after going through a level control for modulating the transmit signal.

#### Local/Repeater operation

When the REPEAT switch on the front panel of the main body is set to ON, the repeater operation is engaged, while when this switch is set to OFF, the full-duplex transceiver operation is engaged.

#### Preset squelch operation

The squelch circuit for the repeater operation which is independent from the main body consists of noise conditioner IC6 (1/2), waveform shaper Q1, microprocessor IC11 and squelch sensitivity adjuster VR1.

The preset squelch level, the hangup timer time and the time-out timer time are compared in IC11 respectively with the voltages at pins 30, 29 and 28 set by VR1, VR2 and VR3 with the reference of the voltage at pin 31 of IC11 and are thus subject to software control.

#### TAKEOVER Switch

The TAKEOVER switch is used to isolate the remote control. (The remote control is isolated when the TAKEOVER switch is pressed.)